## NSN 5961-00-900-0079

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View Online at https://aerobasegroup.com/nsn/5961-00-900-0079 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Field effect **Electrode Internally-electrically Connected To Case:** Gate **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source **Current Rating Per Characteristic:** 0.33 milliamperes zero-gate-voltage drain current **Power Rating Per Characteristic:** 300.0 milliwatts total device dissipation **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: